

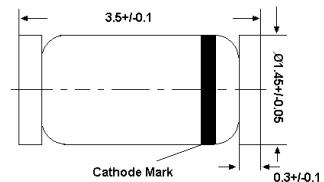
# LL355

## Silicon Epitaxial Planar Switching Diode

### Applications

- High speed switching

LL-34



Glass case MiniMELF  
Dimensions in mm

### Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Value	Unit
Peak Reverse Voltage	$V_{RM}$	90	V
DC Reverse Voltage	$V_R$	80	V
Average Rectified Forward Current	$I_{F(AV)}$	100	mA
Peak Forward Current	$I_{FM}$	225	mA
Peak Forward Surge Current (1 s)	$I_{FSM}$	500	mA
Junction Temperature	$T_j$	150	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	- 55 to + 150	$^\circ\text{C}$

### Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Max.	Unit
Forward Voltage at $I_F = 100 \text{ mA}$	$V_F$	1.2	V
Reverse Current at $V_R = 80 \text{ V}$	$I_R$	0.1	$\mu\text{A}$
Capacitance between Terminals at $V_R = 0.5 \text{ V}$ , $f = 1 \text{ MHz}$	$C_{tot}$	3	pF
Reverse Recovery Time at $I_F = 10 \text{ mA}$ to $I_R = 1 \text{ mA}$ , $V_R = 6 \text{ V}$ , $R_L = 100 \Omega$	$t_{rr}$	4	ns

